Thyristor Semiconductor Device - Page 1 of 1



manufacturer drawing, etc.;

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	losure Material:
Me	
	erall Length:
	25 inches
	erall Diameter:
	tween 1.031 inches and 1.062 inches
	ounting Facility Quantity:
1	
	int Electronic Device Engineering Council/jedec/case Outline Designation:
	94
	bunting Method:
	readed stud
	atures Provided:
	rmetically sealed case
	read Size:
	00 inches
	miconductor Material:
	Itage Rating In Volts Per Characteristic:
	0.0 reverse voltage, peak
	rrent Rating Per Characteristic:
	00 amperes forward current, total rms megahertz
	wer Rating Per Characteristic:
	watts small-signal input power, common-collector blank
	ximum Operating Tempurature Per Measurement Point:
	5.0 degrees celsius ambient air
	st Data Document:
	340-66122 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment m
	cludes any specification, standard or other document that may be referenced in a basic governing drawing)
Th	read Series Designator:
Un	
Те	rminal Type And Quantity:
1 tl	nreaded stud and 2 insulated wire lead w/terminal lug
Sh	elf Life:
N/a	
Un	it Of Measure:
De	militarization:
No	
Fii	g:
A1	10a0